

TECHNICAL DATA
DATA SHEET 4669, REV. PRELIMINARY

# POWER SCHOTTKY RECTIFIER Very Low Reverse Leakage

# **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

### Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Out Performs 200 Volt Ultra Fast Rectifiers

**Maximum Ratings:** 

Annum Rutings.						
Characteristics	Symbol	Condition	Max.	Units		
Peak Inverse Voltage	$V_{RWM}$	-	15	V		
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form Common Cathode (N)/Common Anode(P)	150	A		
Max. Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form Doubler (D)	120	А		
Max. Peak One Cycle Non- Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine wave (per leg)	1000	А		
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.3 \text{A},$ L = 40mH (per leg)	27	mJ		
Repetitive Avalanche Current	I <sub>AR</sub>	$I_{AS}$ decay linearly to 0 in 1 $\mu$ s $f$ limited by $T_J$ max $V_A$ =1.5 $V_R$	1.3	А		
Thermal Resistance	$R_{thJC}$	Per Package	0.2	°C/W		
Max. Junction Temperature	TJ	-	-65 to +100	°C		
Max. Storage Temperature	T <sub>stg</sub>	-	-65 to +100	°C		

## **Electrical Characteristics:**

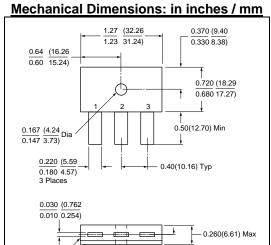
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 120A, Pulse, T <sub>J</sub> = 25 °C (per leg) measured at the leads	0.51	V
	V <sub>F2</sub>	@ 120A, Pulse, T <sub>J</sub> = 125 °C (per leg) measured at the leads	0.47	V
Max. Reverse Current	I <sub>R1</sub>	$@V_R = 15V$ , Pulse, $T_J = 25 °C$ (per leg)	40	mA
	I <sub>R2</sub>	$@V_R = 15V$ , Pulse, $T_J = 125  ^{\circ}C$ (per leg)	2000	mA
Max. Junction Capacitance	Ст	@ $V_R = 5 \text{ V}, T_C = 25 ^{\circ}\text{C}$ $f_{SIG} = 1 \text{ MHz},$ $V_{SIG} = 50 \text{mV} \text{ (p-p) (per leg)}$	7200	pF

Due to the nature of the 15V Schottky devices, some degradation in  $t_{rr}$  performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

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Heat Sink

Epoxy Shell

0.180 (4.57

0.140 3.55)

Vf Curves Shown are for die only.



#### **TECHNICAL DATA**

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